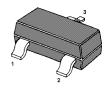
PNP General Purpose Transistor

for amplifier applications

On special request, these transistors can be manufactured in different pin configurations.



Base 2. Emitter 3. Collector
 TO-236 Plastic Package

Absolute Maximum Ratings (T_a = 25 °C)

Parameter	Symbol	Value	Unit
Collector Base Voltage	-V _{CBO}	80	٧
Collector Emitter Voltage	-V _{CES}	80	V
Emitter Base Voltage	-V _{EBO}	4	V
Collector Current	-l _C	500	mA
Power Dissipation	P _{tot}	200	mW
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	357	°C/W
Junction Temperature	Tj	-55 to +150	°C
Storage Temperature Range	T _{Stg}	-55 to +150	°C





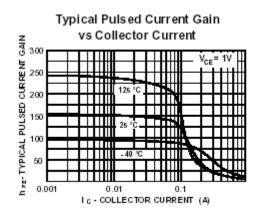


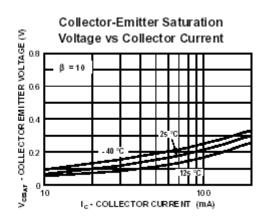




Characteristics at T₂=25 °C

Jnit -
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11/3
nA
ПА
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V
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V
1/
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1/
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41.1-
ЛHz
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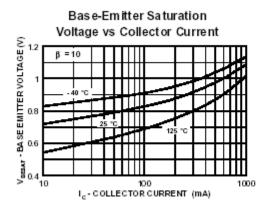


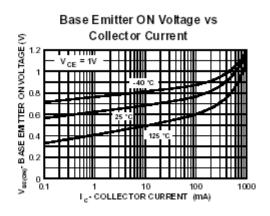


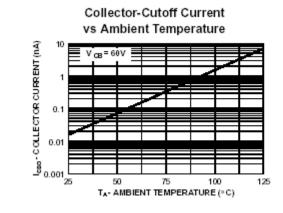


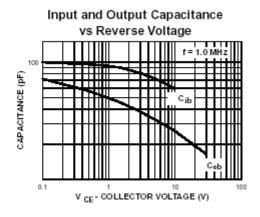


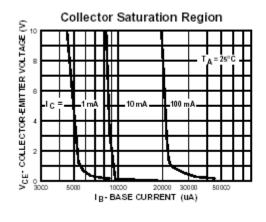


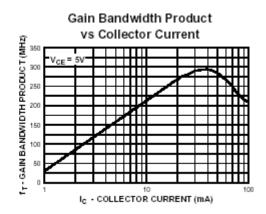
























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